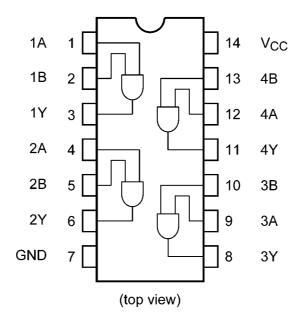
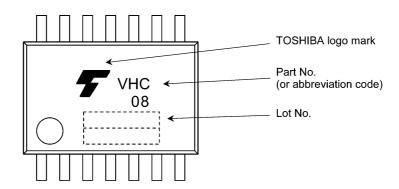


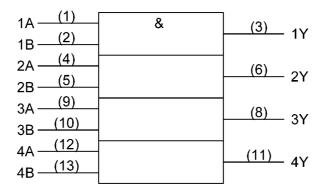
5. Pin Assignment



6. Marking



7. IEC Logic Symbol





8. Truth Table

Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	٧
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	Icc		±50	mA
Power dissipation	P _D	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V_{CC} = 5.0 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	V _{IL}	_		2.0	_		0.50	V
				3.0 to 5.5	_		$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$	I_{OH} = -50 μ A	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I_{OH} = -4 mA	3.0	2.58	_	_	
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	3.0	_	_	0.36	
			I _{OL} = 8 mA	4.5	_	_	0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	2.0	μΑ

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Con	dition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -4 mA	3.0	2.48	_	
			$I_{OH} = -8 \text{ mA}$	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±1.0	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5		20.0	μА



11.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condi	tion	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.40	_	
			I_{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	٧
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.55	
			I _{OL} = 8 mA	4.5	_	0.55	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μΑ

11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Note	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t_{PLH}, t_{PHL}		3.3 ± 0.3	15	_	6.2	8.8	ns
				50	_	8.7	12.3	
			5.0 ± 0.5	15	_	4.3	5.9	
				50	_	5.8	7.9	
Input capacitance	C _{IN}				_	4	10	pF
Power dissipation capacitance	C_{PD}	(Note 1)			_	18		pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/4 \text{ (per gate)}$

11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	3.3 ± 0.3	15	1.0	10.5	ns
			50	1.0	14.0	
		5.0 ± 0.5	15	1.0	7.0	
			50	1.0	9.0	
Input capacitance	C _{IN}				10	pF

11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

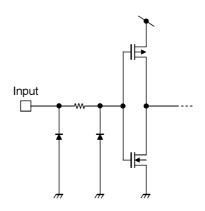
Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t_{PLH}, t_{PHL}		_	3.3 ± 0.3	15	1.0	12.0	ns
					50	1.0	15.5	
				5.0 ± 0.5	15	1.0	8.0	
					50	1.0	10.0	
Input capacitance	C _{IN}		_			_	10	pF



11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

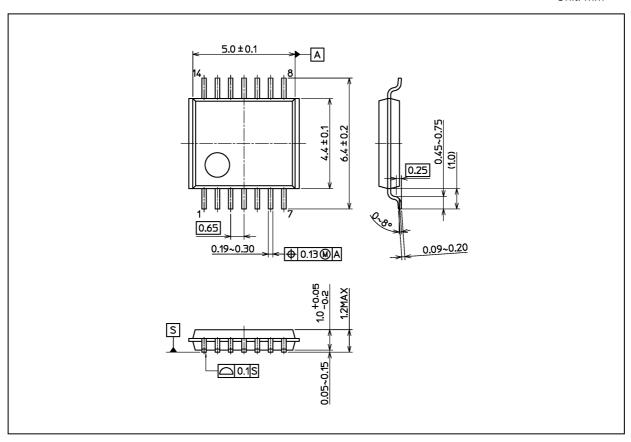
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.3	-0.8	V
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		3.5	V
Maximum low-level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0		1.5	V

11.8. Internal Equivalent Circuit



Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

	Package Name(s)
Nickname: TSSOP14B	



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